

SCHOTTKY BARRIER DUAL DIODE

DESCRIPTION:

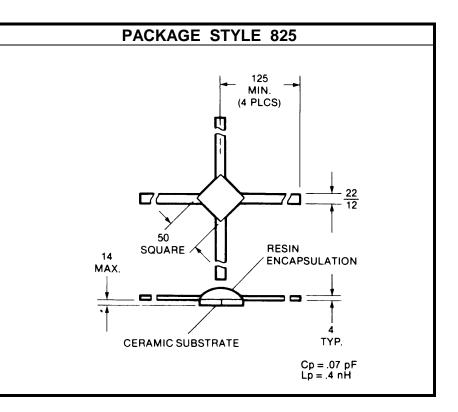
The **5082-2271** is a Low Barrier Schottky Barrier Dual Diode Designed for Single Balanced Mixer, Phase Detector and Modulator Applications up to 4 GHz.

FEATURES INCLUDE:

- Low Barrier
- Excellent Matching
- Replacement for **DMF-3070**

MAXIMUM RATINGS

I _F	100 mA				
P _{DISS}	75 mW @ T _C = 25 ^O C per Junction				
Tj	-65 ^o C to +175 ^o C				
Т _{stg}	-65 °C to +175 °C				
T _{SOLDER}	+235 ^o C for 10 seconds				



CHARACTERISTICS $T_c = 25 °C$

SYMBOL	TEST CONDITIONS	MINIMUM	TYPICAL	MAXIMUM	UNITS
V _F	$I_F = 1 \text{ mA}$	220	250	290	mV
V _{BR}	I _R = 10 μA	2			V
CT	V _R = 0 V f = 1.0 MHz			0.50	pF
R _D	I _F = 10 mA			5	Ω

ADVANCED SEMICONDUCTOR, INC.